

JAN2N6989 Information

Heisener.com

Part Number JAN2N6989

Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Arrays

Description TRANS 4NPN 50V 0.8A TO116

14-DIP (0.300", 7.62mm) **Package**

For the pricing/inventory/lead time, please contact

Website: https://www.heisener.com For Reference Only

E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









JAN2N6989 Specifications

Manufacturer Part Number	JAN2N6989
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Arrays
Package	14-DIP (0.300", 7.62mm)
Series	Military, MIL-PRF-19500/559
Transistor Type	4 NPN (Quad)
Current - Collector (Ic) (Max)	800mA
Voltage - Collector Emitter Breakdown (Max)	50V
Vce Saturation (Max) @ Ib, Ic	1V @ 50mA, 500mA
Current - Collector Cutoff (Max)	10μA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	100 @ 150mA, 10V
Power - Max	1.5W
Frequency - Transition	-
Operating Temperature	-65°C ~ 200°C (TJ)
Mounting Type	Through Hole
Package / Case	14-DIP (0.300", 7.62mm)
Supplier Device Package	TO-116
	Report errors?

JAN2N6989 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

JAN2N6989 Payment Methods









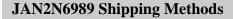
























If you have any question about JAN2N6989, please do not hesitate to contact us!

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